NSN 5962-01-248-9357

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View Online at https://aerobasegroup.com/nsn/5962-01-248-9357

Body Length:		
1.290 inches		
Body Width:		
0.610 inches		
Body Height:		
0.150 inches		
Maximum Power Diss	ipation Rating:	
1.0 watts		
Operating Tempuratu	re Range:	
-55.0/+125.0 degrees o	zelsius	
Storage Tempurature	Range:	
-65.0/+150.0 degrees o	zelsius	
Features Provided:		
Monolithic and bipolar	and programmable	
Inclosure Material:		
Ceramic		
Inclosure Configuration	on:	
Dual-in-line		
Output Logic Form:		
Transistor-transistor log	gic	
Input Circuit Pattern:		
13 input		
Case Outline Source	And Designator:	
D-3 mil-m-38510		
Terminal Surface Trea	atment:	
Solder		
Voltage Rating And T	ype Per Characteristic:	
7.0 volts power source		
Memory Device Type:		
Rom		
Memory Capacity:		
Unknown		
Test Data Document:		
49956-954374 drawing	(this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,	etc
excludes any specificat	tion, standard or other document that may be referenced in a basic governing drawing)	
Terminal Type And Q	uantity:	
24 printed circuit		
Shelf Life:		
N/a		
Unit Of Measure:		
Demilitarization:		
Yes - demil/mli		

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